

SANYO Semiconductors DATA SHEET

2SK3490-

N-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ΙD		8	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	32	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (250mm ² X0.8mm)	1.5	W
		Tc=25°C	3.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =4A	4.8	8		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=4A, VGS=10V		30	39	mΩ
	R _{DS} (on)2	I _D =2A, V _G S=4V		40	56	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		690		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		160		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		88		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		10		ns
Rise Time	tr	See specified Test Circuit.		60		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		27		ns
Fall Time	tf	See specified Test Circuit.		32		ns

Marking: LG Continued on next page.

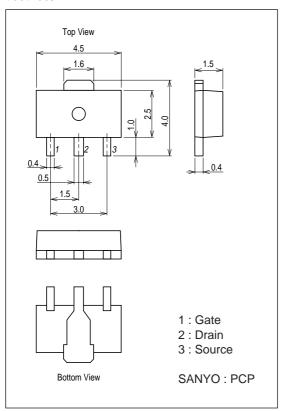
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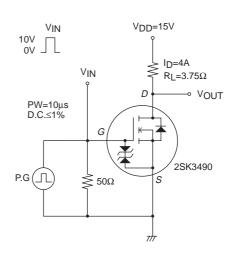
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oill
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =8A		16		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =8A		3.4		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =8A		2.4		nC
Diode Forward Voltage	VSD	IS=8A, VGS=0V		0.85	1.2	V

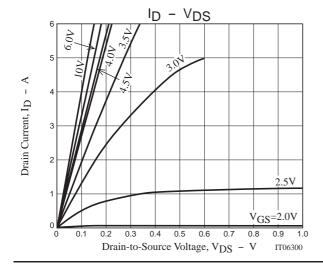
Package Dimensions

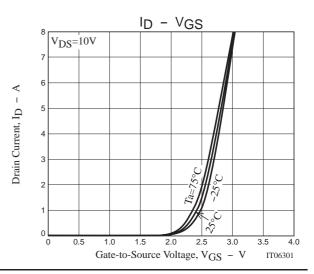
unit : mm 7007-003

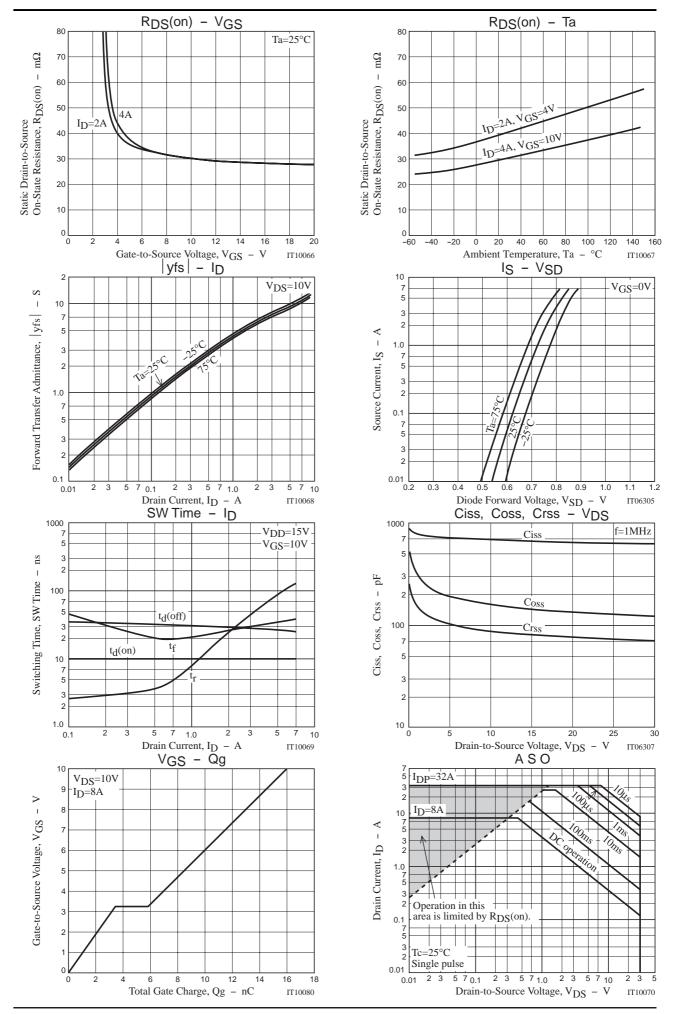


Switching Time Test Circuit

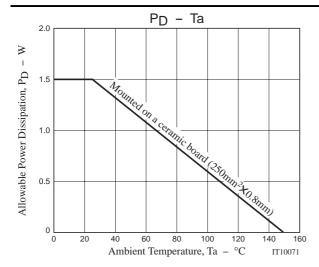


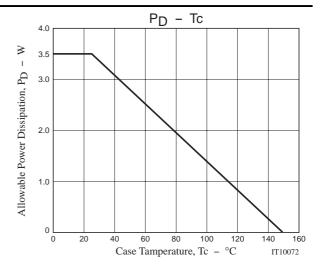






2SK3490





Note on usage: Since the 2SK3490 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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